







SN74LVC00A-Q1

SCAS703D - SEPTEMBER 2003 - REVISED MAY 2024

SN74LVC00A-Q1 Automotive Quadruple 2-Input Positive-NAND Gate

1 Features

- Qualified for automotive applications
- Operates from 2V to 3.6V
- Inputs accept voltages to 5.5V
- Max t_{pd} of 4.3ns at 3.3V
- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} $= 3.3V, T_A = 25$ °C
- Typical V_{OHV} (output V_{OH} undershoot) > 2V at V_{CC} $= 3.3V, T_A = 25$ °C

2 Description

The SN74LVC00A-Q1 quadruple 2-input positive-NAND gate is designed for 2.7V to 3.6V V_{CC} operation.

The device performs the Boolean function $Y = \overline{A \cdot B}$ or $Y = \overline{A} + \overline{B}$ in positive logic.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE(2)	BODY SIZE(3)
	BQA (WQFN, 14)	3mm × 2.5mm	3mm × 2.5mm
SN74LVC00A-Q1	D (SOIC, 14)	8.65mm × 6mm	8.65mm × 3.9mm
	PW (SOP, 14)	5mm × 6.4mm	5mm × 4.4mm

- For more information, see Section 10.
- (2) The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.



Logic Diagram, Each Gate (Positive Logic)



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3 Pin Configuration and Functions

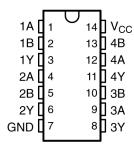


Figure 3-1. SN74LVC00A-Q1 D or PW Package, 14-Pin SOIC or TSSOP (Top View)

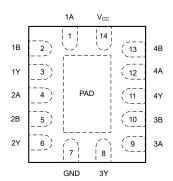


Figure 3-2. SN74LVC00A-Q1 BQA Package, 14-PIN WQFN (Top View)

Table 3-1. Pin Functions

	PIN		DESCRIPTION
NAME	NO.	TYPE ⁽¹⁾	DESCRIPTION
1A	1	I	Channel 1, Input A
1B	2	I	Channel 1, Input B
1Y	3	0	Channel 1, Output Y
2A	4	I	Channel 2, Input A
2B	5	I	Channel 2, Input B
2Y	6	0	Channel 2, Output Y
GND	7	_	Ground
3Y	8	0	Channel 3, Output Y
3A	9	Į	Channel 3, Input A
3B	10	I	Channel 3, Input B
4Y	11	0	Channel 4, Output Y
4A	12	I	Channel 4, Input A
4B	13	I	Channel 4, Input B
V _{CC}	14	_	Positive Supply
Thermal Info	rmation	_	The thermal pad can be connected to GND or left floating. Do not connect to any other signal or supply.

⁽¹⁾ Signal Types: I = Input, O = Output, I/O = Input or Output, P = Power Supply, G = Ground.



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
V _{CC}	Supply voltage range			-0.5	6.5	V
VI	Input voltage range ⁽¹⁾		-0.5	6.5	V	
Vo	Output voltage range ^{(1) (2)}		-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0			-50	mA
I _{OK}	Output clamp current	V _O < 0			-50	mA
Io	Continuous output current			±50	mA	
	Continuous current through V _{CC} or GND			±100	mA	
T _{stg}	Storage temperature range			-65	150	°C

⁽¹⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

4.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V

⁽¹⁾ AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

4.3 Recommended Operating Conditions

			MIN	MAX	UNIT
.,	Supply voltage	Operating	2	3.6	V
V _{CC}	Supply voltage	Data retention only	1.5		V
V _{IH}	High-level input voltage	V _{CC} = 2.7V to 3.6V	2		V
V _{IL}	Low-level input voltage	V _{CC} = 2.7V to 3.6V		0.8	V
VI	V _I Input voltage		0	5.5	V
Vo	Output voltage		0	V_{CC}	V
	High lovel output current	V _{CC} = 2.7V		-12	mA
Іон	High-level output current	V _{CC} = 3V		-24	ША
1	Law lavel output current	V _{CC} = 2.7V		12	mA
I _{OL}	Low-level output current $V_{CC} = 3V$			24	ША
T _A	Operating free-air temperature		-40	125	°C

4.4 Thermal Information

			SN74LVC00A-Q1		
THERMAL METRIC ⁽¹⁾		BQA	D	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	102.3	127.8	150.8	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Product Folder Links: SN74LVC00A-Q1

The value of V_{CC} is provided in the recommended operating conditions table.

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP ⁽¹⁾ MAX	UNIT	
V _{OH}	I _{OH} = -100μA	2.7V to 3.6V	V _{CC} - 0.2			
	I _{OH} = -12mA	2.7V	2.2		\ _V	
	10H12111A	3V	2.4		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
	I _{OH} = -24mA	3V	2.2			
V _{OL}	I _{OL} = 100μA	2.7V to 3.6V		0.2		
	I _{OL} = 12mA	2.7V		0.4	V	
	I _{OL} = 24mA	3V		0.55		
I _I	V _I = 5.5V or GND	3.6V		±5	μΑ	
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	3.6V		10	μΑ	
ΔI _{CC}	One input at $V_{CC} - 0.6V$, Other inputs at V_{CC} or GND	2.7V to 3.6V		500	μΑ	
C _i	$V_I = V_{CC}$ or GND	3.3V		5	pF	

⁽¹⁾ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		UNIT
			MIN	MAX	MIN	MAX	
t _{pd}	A or B	Y		5.1	1	4.3	ns

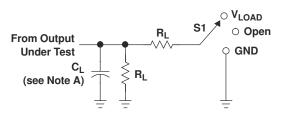
4.7 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{CC} = 2.5V TYP	V _{CC} = 3.3V TYP	UNIT
C _{pd}	Power dissipation capacitance per gate	f = 10MHz	18	19	pF



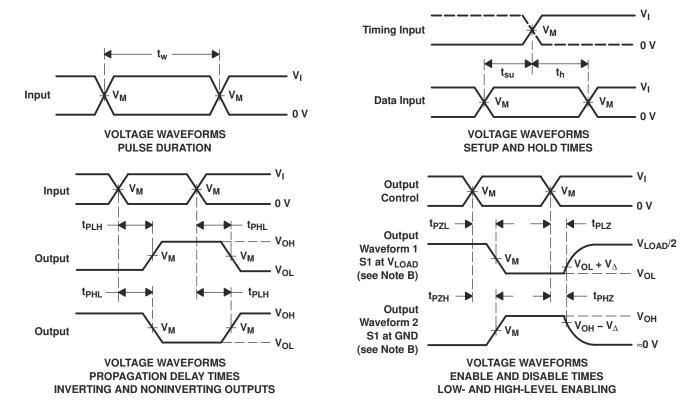
5 Parameter Measurement Information



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL}	V _{LOAD}
t _{PHZ} /t _{PZH}	GND

LOAD	CIRCUIT	

V	INF	PUTS	.,	V	0		.,	
V _{CC}	V_{I}	t _r /t _f	V _M	V _{LOAD}	CL	R _L	V_Δ	
1.8 V \pm 0.15 V	V _{CC}	≤2 ns	V _{CC} /2	2×V _{CC}	30 pF	1 k Ω	0.15 V	
2.5 V \pm 0.2 V	v_{cc}	≤2 ns	V _{CC} /2	2 × V _{CC}	30 pF	500 Ω	0.15 V	
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	
3.3 V \pm 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V	



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.

Figure 5-1. Load Circuit and Voltage Waveforms

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6 Detailed Description

6.1 Functional Block Diagram



Figure 6-1. Logic Diagram, Each Gate (Positive Logic)

6.2 Device Functional Modes

Function Table (Each Gate)

INP	UTS	OUTPUT
Α	В	Y
Н	Н	L
L	X	Н
X	L	Н



7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in given example layout image.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must never be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or $V_{\rm CC}$, whichever makes more sense for the logic function or is more convenient.

7.2.2 Layout Example

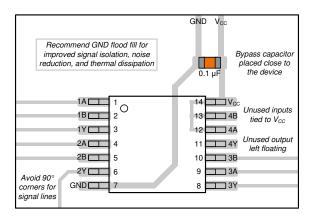


Figure 7-1. Example Layout for the SN74LVC00A-Q1

Product Folder Links: SN74LVC00A-Q1

8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Documentation Support

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LVC00A-Q1	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Notifications to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (March 2024) to Revision D (May 2024)

Page

Updated RθJA values: PW = 113 to 150.8, all values in °C/W4

Changes from Revision B (February 2008) to Revision C (March 2024)

Page

Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and



•	Added BQA package to Package Information table, Pin Configuration and Functions section, and Thermal
	Information table1
•	Updated RθJA values: D = 86 to 127.8, all values in °C/W

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LVC00A-Q1

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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LVC00AQPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00AQ	Samples
SN74LVC00AQPWRQ1	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 125	LVC00AQ	Samples
SN74LVC00AWBQARQ1	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LVC00Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC00A-Q1:

◆ Catalog : SN74LVC00A

● Enhanced Product : SN74LVC00A-EP

■ Military : SN54LVC00A

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

• Military - QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC00AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC00AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC00AQPWRG4Q1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC00AQPWRQ1	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74LVC00AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
 - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



2.5 x 3, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

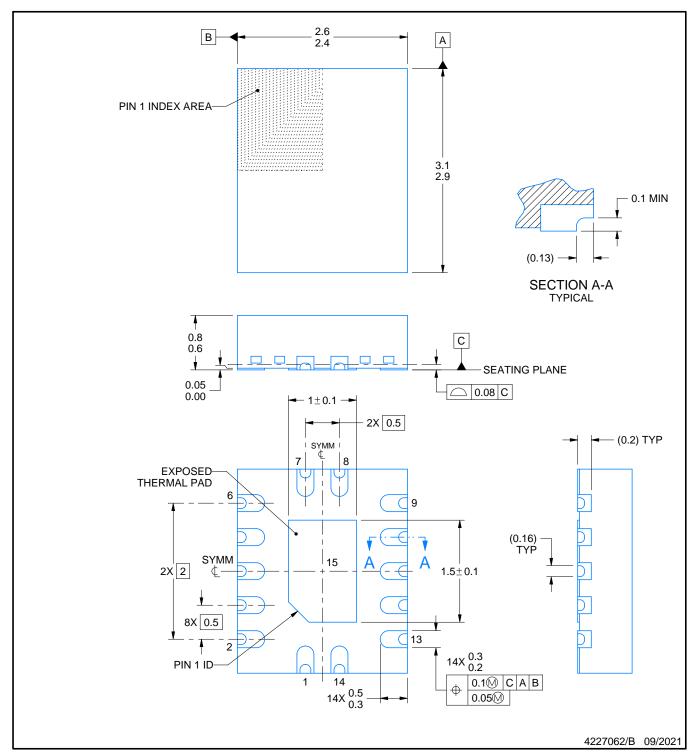
This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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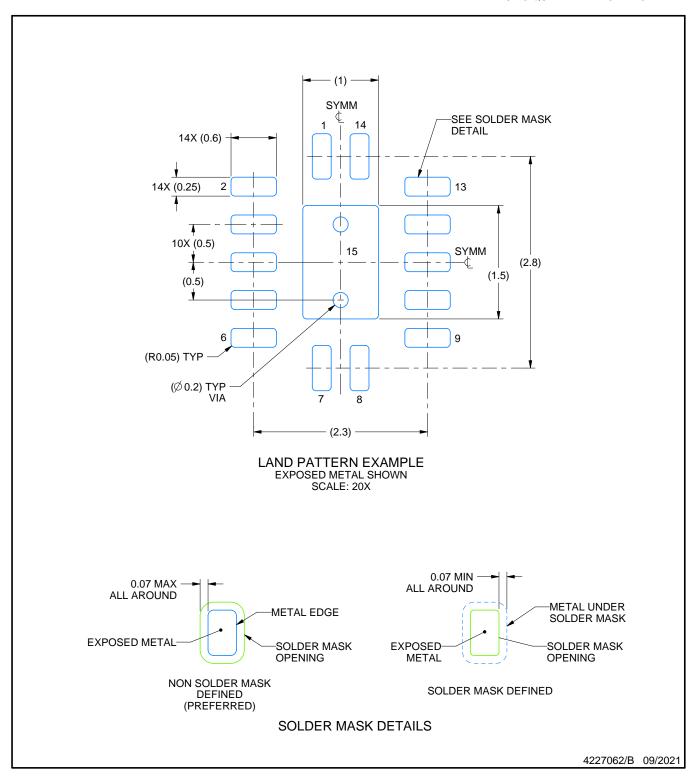


NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD

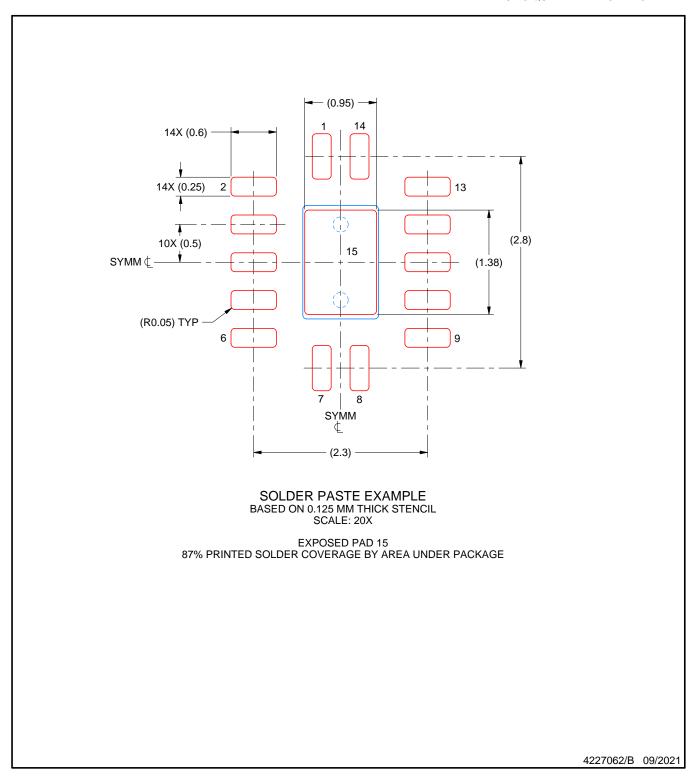


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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